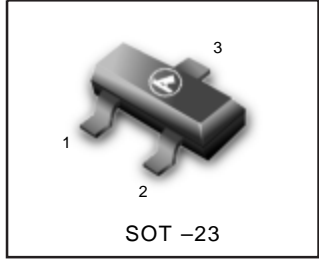


Dual Series Switching Diodes

LDAN217LT1G

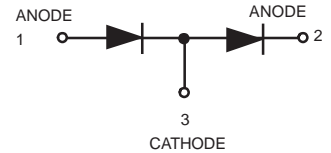


FEATURES

- Ultra high speed switching
- Suitable for high packing density layout.
- High reliability.
- We declare that the material of product is ROHS compliant and halogen free.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LDAN217LT1G	A7	3000/Tape&Reel
LDAN217LT3G	A7	10000/Tape&Reel



MAXIMUM RATINGS (Each Diode)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	80	Vdc
Forward Current	I_o	100	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	300	mAdc
Forward voltage($I_f = 100mA$)	V_F	1.2	V
Reverse current ($V_r = 70V$)	I_R	0.1	μA
Reverse recovery time($V_r = 6V, I_f = 5 mA$)	T_{rr}	4	nS

ELECTRICAL CHARACTERISTIC CURVES

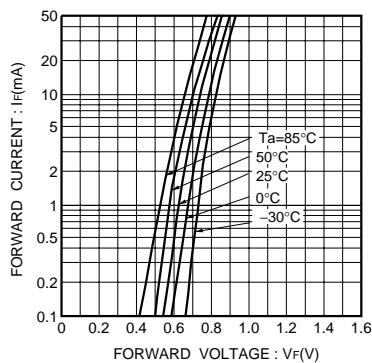


Fig.1 Forward characteristics

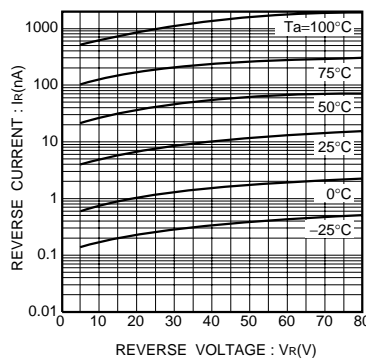


Fig.2 Reverse characteristics

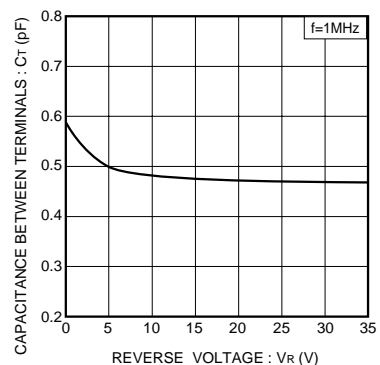


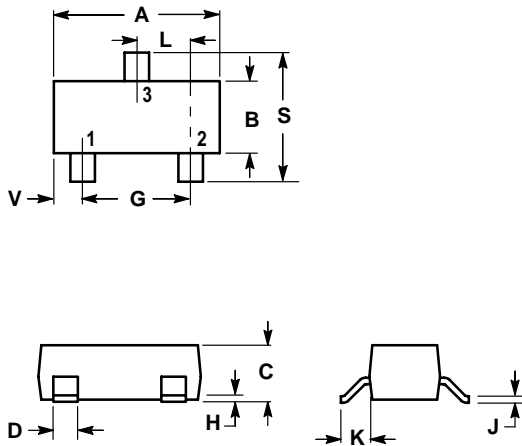
Fig.3 Capacitance between terminals characteristics

LDAN217LT1G

SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

